PATENT S/N 09/489954

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Examiner: Donghee Kang Pierre C. Fazan et al. Applicant:

> Group Art Unit: 2811 09/489954

Serial No.: Docket: 303.434US2 Filed: January 24, 2000

METHOD FOR FORMING A STORAGE CELL CAPACITOR COMPATIBLE Title:

WITH HIGH DIELECTRIC CONSTANT MATERIALS

COMMUNICATION CONCERNING RELATED APPLICATION(S)

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Applicants would like to bring to the Examiner's attention the following related application(s) in the above-identified patent application:

<u>Serial/Patent No.</u> 08/044331	Filing Date April 2, 1993	Attorney Docket 303.433US1	Title METHOD FOR FORMING A STORAGE CELL CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS
08/390336 5478772	February 17, 1995	303.433US2	METHOD FOR FORMING A STORAGE CELL CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS
08/572392 6030847	December 14, 1995	303.434US1	METHOD FOR FORMING A STORAGE CELL CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS
08/104524 5392189	August 10, 1993	303.445US1	CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS HAVING TWO INDEPENDENT INSULATIVE LAYERS AND THE METHOD FOR FORMING SAME

COMMUNICATION CONCERNING RELATED APPLICATIONS

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Title: METHOD FOR FORMING A STORAGE CELL CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS

08/314117 6066528	September 27, 1994	303.445US2	CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS HAVING TWO INDEPENDENT INSULATIVE LAYERS AND THE METHOD FOR FORMING SAME
09/357634 6495427	July 20, 1999	303.445US3	METHOD FOR FORMING A CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS HAVING TWO INDEPENDENT INSULATIVE LAYERS
08/104525 5381302	August 10, 1993	303.446US1	CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS HAVING A LOW CONTACT RESISTANCE LAYER AND THE METHOD FOR FORMING SAME
08/313677 5506166	September 27, 1994	303.446US2	CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS HAVING A LOW CONTACT RESISTANCE LAYER AND THE METHOD FOR FORMING SAME
08/572846 5959327	December 14, 1995	303.446US3	CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS HAVING A LOW CONTACT RESISTANCE LAYER AND THE METHOD FOR FORMING SAME
09/362326 6531730	July 27, 1999	303.446US4	CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS HAVING A LOW CONTACT RESISTANCE LAYER AND THE METHOD FOR FORMING SAME

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Respectfully submitted,

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I hereby certify that this paper is being transmitted by facsimile to the U.S. Patent and Trademark Office on the date shown below.

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